National Semiconductor

September 1998

54ACTQ02
Quad 2-Input NOR Gate

General Description

The 'ACTQ02 contains four, 2-input NOR gates.

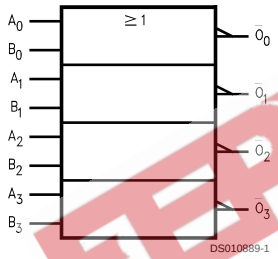
The 'ACTQ utilize NSC Quiet Series technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series® features GTO® output control and undershoot corrector in addition to a split ground bus for superior ACMOS performance.

Features

- I_{CC} reduced by 50%
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Improved latch-up immunity
- Minimum 4 kV ESD protection
- Outputs source/sink 24 mA
- 'ACTQ02 has TTL-compatible inputs
- Standard Microcircuit Drawing (SMD) 5962-9218101

Logic Symbol

IEEE/IEC

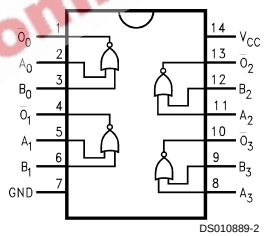


DS010889-1

Pin Names	Description
A_n, B_n	Inputs
$\overline{O}_n$	Outputs

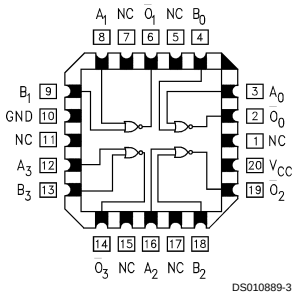
Connection Diagrams

Pin Assignment for DIP and Flatpak



DS010889-2

Pin Assignment for LCC



DS010889-3

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Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65˚C to +150˚C
DC Latch-Up Source or Sink Current	±300 mA
Junction Temperature (T_J)	
CDIP	175˚C

Recommended Operating Conditions

Supply Voltage (V_{CC})	
'ACTQ	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	
54ACTQ	−55˚C to +125˚C
Minimum Input Edge Rate (ΔV/Δt)	
'ACTQ Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. National does not recommend operation of FACT™ circuits outside databook specifications.

DC Characteristics for 'ACTQ Family Devices

Symbol	Parameter	V_{CC} (V)	54ACTQ T_A = −55˚C to +125˚C Guaranteed Limits	Units	Conditions
V_{IH}	Minimum High Level Input Voltage	4.5	2.0	V	V_{OUT} = 0.1V
		5.5	2.0		or V_{CC} − 0.1V
V_{IL}	Maximum Low Level Input Voltage	4.5	0.8	V	V_{OUT} = 0.1V
		5.5	0.8		or V_{CC} − 0.1V
V_{OH}	Minimum High Level Output Voltage	4.5	4.4	V	I_{OUT} = −50 μA
		5.5	5.4		
					V_{IN} = V_{IL} or V_{IH}
		4.5	3.70	V	I_{OH} = −24 mA
		5.5	4.70		I_{OH} = −24 mA
V_{OL}	Maximum Low Level Output Voltage	4.5	0.1	V	I_{OUT} = 50 μA
		5.5	0.1		
					V_{IN} = V_{IL} or V_{IH}
		4.5	0.50	V	I_{OL} = 24 mA
		5.5	0.50		I_{OL} = 24 mA
I_{IN}	Maximum Input Leakage Current	5.5	±1.0	μA	V_I = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	1.6	mA	V_I = V_{CC} − 2.1V
I_{OLD}	Minimum Dynamic Output Current (Note 2)	5.5	50	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5	−50	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5	40.0	μA	V_{IN} = V_{CC} or GND (Note 3)
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	5.0	1.5	V	(Note 4)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	5.0	-1.2	V	(Note 4)

Note 2: Maximum test duration 2.0 ms, one output loaded at a time.

Note 3: I_{CC} for 54ACTQ @ 25˚C is identical to 74ACTQ @ 25˚C.

Note 4: Max number of outputs defined as (n). Data inputs are 0V to 3V. One output @ GND.

AC Electrical Characteristics

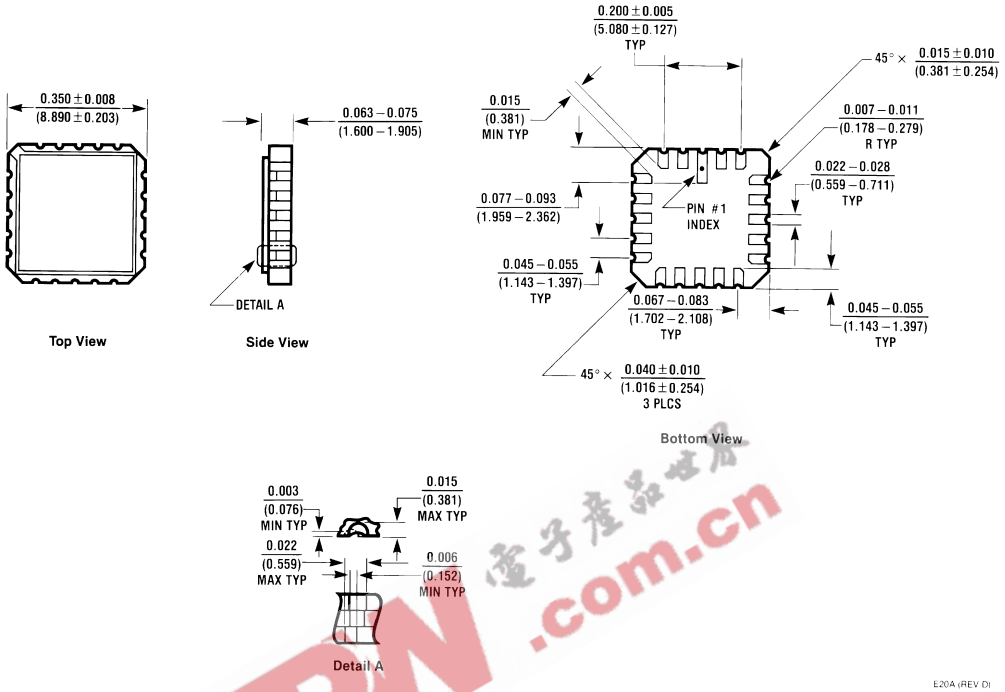
Symbol	Parameter	V_{CC} (V) (Note 5)	54ACTQ T_A = −55°C to +125°C C_L = 50 pF		Units	Fig. No.
			Min	Max		
t_{PLH}	Propagation Delay Data to Output	5.0	1.5	9.5	ns	
t_{PHL}	Propagation Delay Data to Output	5.0	1.5	9.5	ns	

Note 5: Voltage Range 5.0 is 5.0V ±0.5V

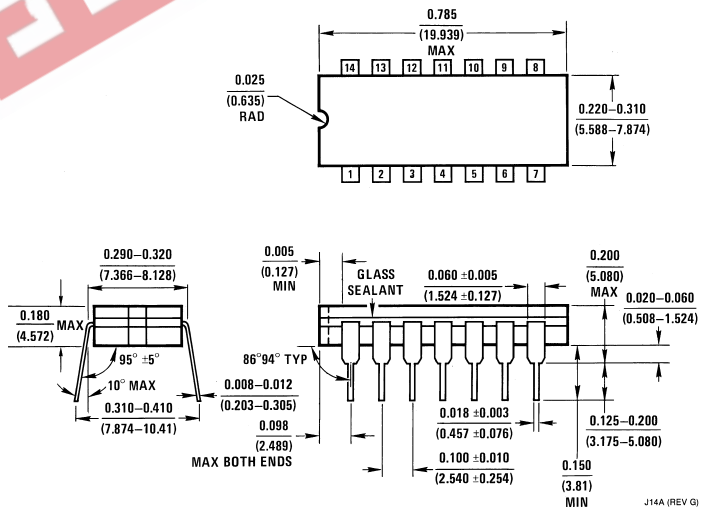
Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	75	pF	V_{CC} = 5.0V

Physical Dimensions inches (millimeters) unless otherwise noted

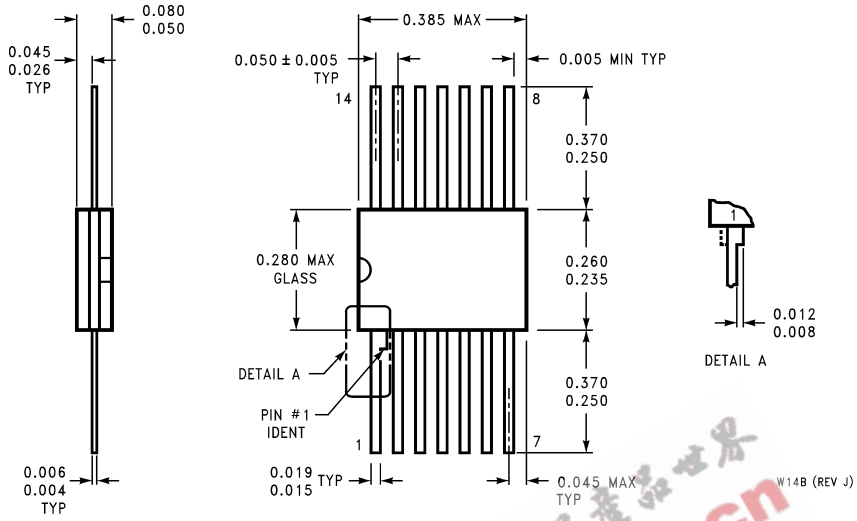


20-Terminal Ceramic Leadless Chip Carrier (L)
NS Package Number E20A



14-Lead Ceramic Dual-In-Line Package (D)
NS Package Number J14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Ceramic Flatpak (F)
NS Package Number W14B

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